650 V, 50 mΩ Gallium Nitride (GaN) FET 27 November 2019

Product data sheet

1. General description

The GAN063-650WSA is a 650 V, 50 mΩ Gallium Nitride (GaN) FET. It is a normally-off device that combines Nexperia's state-of-the-art high-voltage GaN HEMT and low-voltage silicon MOSFET technologies — offering superior reliability and performance. AEC-Q101 qualified.

2. Features and benefits

- Ultra-low reverse recovery charge
- Simple gate drive (0 V to +10 V or 12 V)
- Robust gate oxide (±20 V capability)
- · High gate threshold voltage (+4 V) for very good gate bounce immunity
- Very low source-drain voltage in reverse conduction mode
- Transient over-voltage capability (800 V)
- AEC-Q101 qualified

3. Applications

- Hard and soft switching converters for industrial and datacom power
- Bridgeless totempole PFC
- PV and UPS inverters
- Servo motor drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	-55 °C ≤ T _j ≤ 175 °C	-	-	650	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	34.5	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	-	143	W
Tj	junction temperature		-55	-	175	°C
Static char	acteristics					
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}$	-	50	60	mΩ
Dynamic c	haracteristics					
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 400 V; V _{GS} = 10 V;	-	4	-	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C	-	15	-	nC
Source-dra	nin diode					
Q _r	recovered charge	$I_S = 25 \text{ A}; dI_S/dt = -1000 \text{ A/}\mu\text{s};$ $V_{GS} = 0 \text{ V}; V_{DS} = 400 \text{ V}; Fig. 14$	-	125	-	nC



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	S	source		
3	D	drain		
mb	S	mounting base; connected to source		G
			TO-247 (SOT429)	aaa-028116

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
GAN063-650WSA	TO-247	plastic, single-ended through-hole package; 3 leads; 5.45 mm pitch; 20.45 mm x 15.6 mm x 4.95 mm body	SOT429		

7. Marking

Table 4. Marking codes

Type number	Marking code
GAN063-650WSA	GAN063-650WSA

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
drain-source voltage	-55 °C ≤ T _j ≤ 175 °C	-	650	V
transient drain to source voltage	pulsed; $t_p = 1 \mu s$; $\delta_{factor} = 0.01$	-	800	V
gate-source voltage		-20	20	V
total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	143	W
drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	34.5	Α
	V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	24.4	Α
peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 3	-	150	Α
storage temperature		-55	175	°C
junction temperature		-55	175	°C
peak soldering temperature		-	260	°C
n diode				
source current	T _{mb} = 25 °C; V _{GS} = 0 V	-	34.5	Α
peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C	-	150	Α
	drain-source voltage transient drain to source voltage gate-source voltage total power dissipation drain current peak drain current storage temperature junction temperature peak soldering temperature n diode source current	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	drain-source voltage $-55\ ^\circ \text{C} \le T_j \le 175\ ^\circ \text{C}$ - 650 transient drain to source voltage pulsed; $t_p = 1\ \mu \text{s};\ \delta_{\text{factor}} = 0.01$ - 800 gate-source voltage -20 20 total power dissipation $T_{mb} = 25\ ^\circ \text{C};\ \text{Fig. 1}$ - 143 drain current $V_{GS} = 10\ \text{V};\ T_{mb} = 25\ ^\circ \text{C};\ \text{Fig. 2}$ - 24.4 peak drain current pulsed; $t_p \le 10\ \mu \text{s};\ T_{mb} = 25\ ^\circ \text{C};\ \text{Fig. 3}$ - 150 storage temperature pulsed; $t_p \le 10\ \mu \text{s};\ T_{mb} = 25\ ^\circ \text{C};\ \text{Fig. 3}$ - 260 total power dissipation $T_{mb} = 25\ ^\circ \text{C};\ T_{mb} $

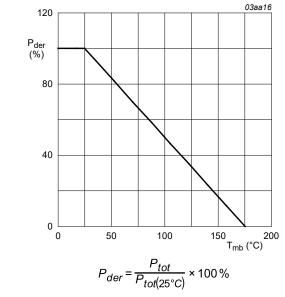
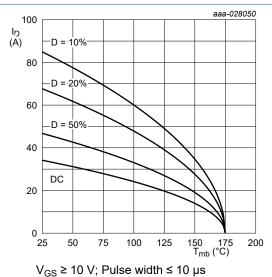
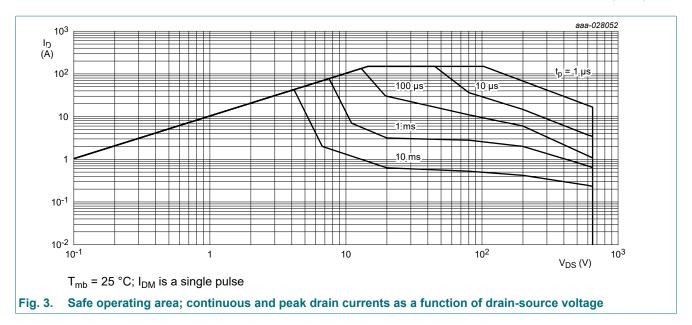


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$; Pulse width $\le 10 \text{ µs}$

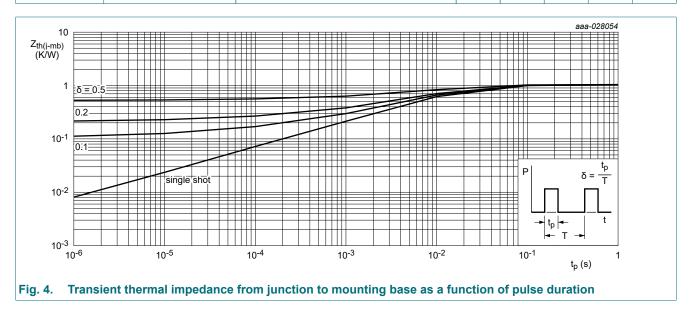
Fig. 2. Drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	-	1.05	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in free air	-	-	40	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	3.4	3.9	4.5	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _i = 175 °C; <u>Fig. 9</u>	2.2	-	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _i = -55 °C; <u>Fig. 9</u>	-	-	5.2	V
I _{DSS}	drain leakage current	V _{DS} = 650 V; V _{GS} = 0 V; T _i = 25 °C	-	2	25	μA
		V _{DS} = 650 V; V _{GS} = 0 V; T _j = 175 °C	-	25	-	μA
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C	-	50	60	mΩ
	resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 10	-	120	-	mΩ
R _G	gate resistance	f = 1 MHz	-	2.3	-	Ω
Dynamic ch	naracteristics		l			
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 400 V; V _{GS} = 10 V;	-	15	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	6	-	nC
Q _{GD}	gate-drain charge	1	-	4	-	nC
C _{iss}	input capacitance	V _{DS} = 400 V; V _{GS} = 0 V; f = 1 MHz;	-	1000	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 11</u>	-	130	-	pF
C _{rss}	reverse transfer capacitance		-	8	-	pF
C _{o(er)}	effective output capacitance, energy related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. } 12$	-	190	-	pF
C _{o(tr)}	effective output capacitance, time related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}$	-	310	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 400 \text{ V}; R_L = 16 \Omega; V_{GS} = 12 \text{ V};$	-	57	-	ns
t _r	rise time	$R_{G(ext)} = 40 \Omega$	-	10	-	ns
t _{d(off)}	turn-off delay time	1	-	88	-	ns
t _f	fall time	1	-	11	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 400 V	-	125	-	nC
Source-dra	in diode				<u> </u>	
V_{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 13</u>	-	1.9	-	V
		I _S = 12.5 A; V _{GS} = 0 V; T _j = 25 °C	-	1.35	-	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -1000 \text{ A/}\mu\text{s};$	-	54	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = 400 V; <u>Fig. 14</u>	-	125	-	nC

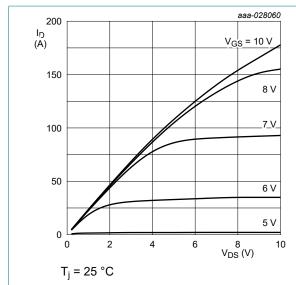


Fig. 5. Output characteristics; drain current as a function of drain-source voltage; typical values

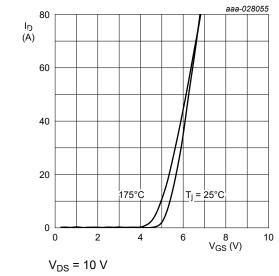


Fig. 7. Transfer characteristics; drain current as a function of gate-source voltage; typical values

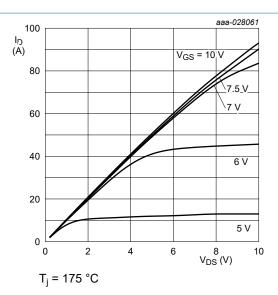


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

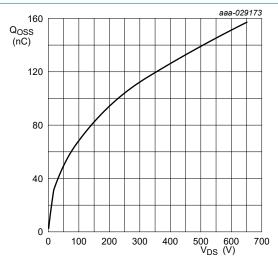


Fig. 8. Typical QOSS

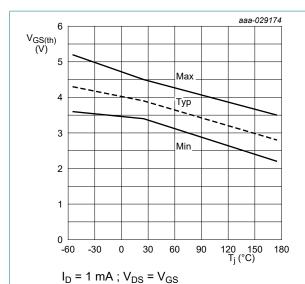


Fig. 9. Gate-source threshold voltage as a function of junction temperature

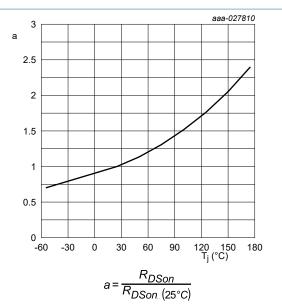


Fig. 10. Normalized drain-source on-state resistance factor as a function of junction temperature

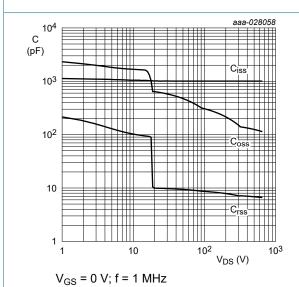


Fig. 11. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

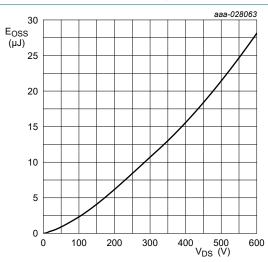


Fig. 12. Typical COSS Stored Energy

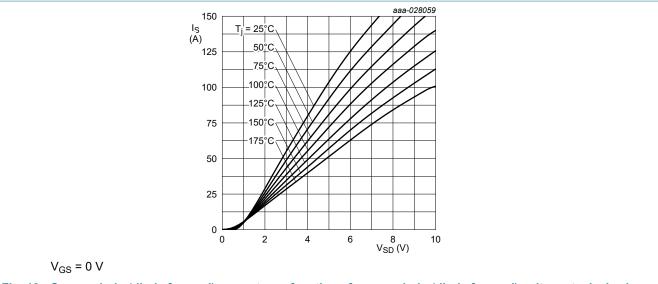
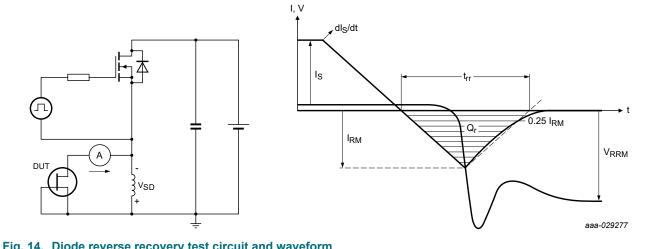


Fig. 13. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

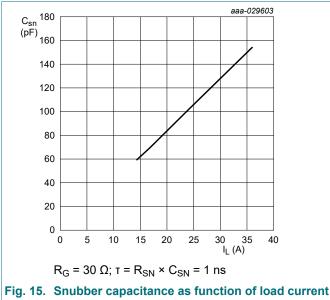


11. Application information

To achieve maximum efficiency and stability when switching high currents, a switching node RC snubber (R_{sn}, C_{sn}) is recommended. For I_L < 14 A, a switching-node snubber is not required.

C_{SN} is taken from the graph.

R_{SN} should be selected to achieve a time constant of 1 ns; e.g. if C_{SN} = 100 pF, $R_{SN} = 1 \text{ ns} / 100 \text{ pF} = 10 \Omega.$



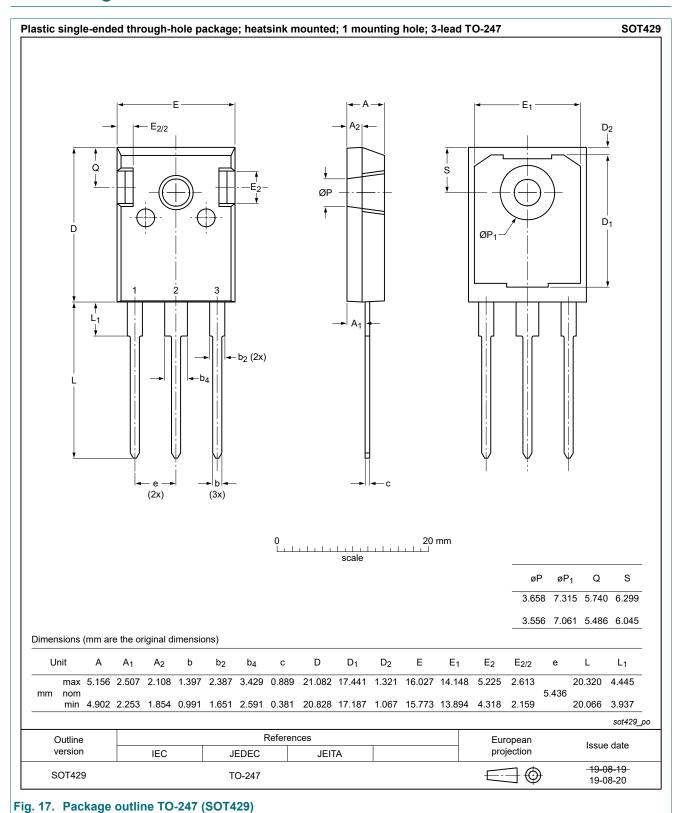
DC bus -o V_{BUS} RC_{DCL} (place as close as possible to drain pin) Q₁ Rg RSN RCSN CSN aaa-029331

Fig. 16. DC-link snubber circuit



Note: A DC-link snubber is recommended in all cases. Optimal is 20 nF in series with 4 Ω , most easily achieved with parallel combination 10 nF and 8 Ω . This snubber lowers the Q factor of any resonance in the bus. That resonance will act as a load on the high gain amplifier that is the GaN FET and can lead to instability. For very high current, an RC snubber is recommended for the switching node. This will increase switching loss, so this is only recommended at high power levels where the losses are a very small percentage of the total power.

12. Package outline



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	. Characteristics	5
11.	Application information	9
12.	Package outline	10
	. Legal information	
	-	

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 27 November 2019

12 / 12

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